

**MOTOROLA**  
**SEMICONDUCTOR**  
**TECHNICAL DATA**

T-41-83

## 6-Pin DIP Optoisolators

### Transistor Output

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector.

- Convenient Plastic Dual-in-Line Package
- Guaranteed 70 Volt  $V_{(BR)CEO}$  Minimum
- High Input-Output Isolation Guaranteed — 7500 Volts Peak
- UL Recognized. File Number E54915 
- VDE approved per standard 0883/6.80 (Certificate number 41853), with additional approval to DIN IEC380/VDE0806, IEC435/VDE0805, IEC65/VDE0860, VDE0110b, covering all other standards with equal or less stringent requirements, including IEC204/VDE0113, VDE0160, VDE0832, VDE0833, etc. 
- Special lead form available (add suffix "T" to part number) which satisfies VDE0883/6.80 requirement for 8 mm minimum creepage distance between input and output solder pads.
- Various lead form options available. Consult "Optoisolator Lead Form Options" data sheet for details.

**CNY17-1**  
**CNY17-2**  
**CNY17-3**
**6-PIN DIP**  
**OPTOISOLATORS**  
**TRANSISTOR OUTPUT**

**CASE 730A-02**  
**PLASTIC**
**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Rating                                                                                       | Symbol           | Value | Unit                 |
|----------------------------------------------------------------------------------------------|------------------|-------|----------------------|
| <b>INPUT LED</b>                                                                             |                  |       |                      |
| Reverse Voltage                                                                              | $V_R$            | 6     | Volts                |
| Forward Current — Continuous                                                                 | $I_F$            | 60    | mA                   |
| Forward Current — Pk ( $PW = 1 \mu\text{s}$ , 330 pps)                                       | $I_F(\text{pk})$ | 1.5   | A                    |
| LED Power Dissipation @ $T_A = 25^\circ\text{C}$<br>with Negligible Power in Output Detector | $P_D$            | 120   | mW                   |
| Derate above $25^\circ\text{C}$                                                              |                  | 1.41  | mW/ $^\circ\text{C}$ |

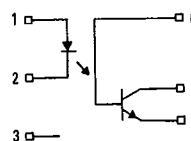
**OUTPUT TRANSISTOR**

|                                                                                             |           |      |                      |
|---------------------------------------------------------------------------------------------|-----------|------|----------------------|
| Collector-Emitter Voltage                                                                   | $V_{CEO}$ | 70   | Volts                |
| Emitter-Base Voltage                                                                        | $V_{EBO}$ | 7    | Volts                |
| Collector-Base Voltage                                                                      | $V_{CBO}$ | 70   | Volts                |
| Collector Current — Continuous                                                              | $I_C$     | 100  | mA                   |
| Detector Power Dissipation @ $T_A = 25^\circ\text{C}$<br>with Negligible Power in Input LED | $P_D$     | 150  | mW                   |
| Derate above $25^\circ\text{C}$                                                             |           | 1.76 | mW/ $^\circ\text{C}$ |

**TOTAL DEVICE**

|                                                                                              |           |             |                            |
|----------------------------------------------------------------------------------------------|-----------|-------------|----------------------------|
| Isolation Surge Voltage (1)<br>(Peak ac Voltage, 60 Hz, 1 sec Duration)                      | $V_{ISO}$ | 7500        | Vac                        |
| Total Device Power Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$     | 250<br>2.94 | mW<br>mW/ $^\circ\text{C}$ |
| Ambient Operating Temperature Range                                                          | $T_A$     | -55 to +100 | $^\circ\text{C}$           |
| Storage Temperature Range                                                                    | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$           |
| Soldering Temperature (10 sec, 1/16" from case)                                              | $T_{sol}$ | 260         | $^\circ\text{C}$           |

(1) Isolation surge voltage is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

**SCHEMATIC**


1. LED ANODE  
 2. LED CATHODE  
 3. N.C.  
 4. EMITTER  
 5. COLLECTOR  
 6. BASE

T-41-83

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic                                                                                                                 | Symbol | Min | Typ                 | Max            | Unit          |
|--------------------------------------------------------------------------------------------------------------------------------|--------|-----|---------------------|----------------|---------------|
| <b>INPUT LED</b>                                                                                                               |        |     |                     |                |               |
| Forward Voltage ( $I_F = 60\text{ mA}$ )<br>$T_A = 25^\circ\text{C}$<br>$T_A = -55^\circ\text{C}$<br>$T_A = 100^\circ\text{C}$ | $V_F$  | —   | 1.35<br>1.5<br>1.25 | 1.65<br>—<br>— | Volts         |
| Reverse Leakage Current ( $V_R = 6\text{ V}$ )                                                                                 | $I_R$  | —   | —                   | 10             | $\mu\text{A}$ |
| Capacitance ( $V = 0$ , $f = 1\text{ MHz}$ )                                                                                   | $C_J$  | —   | 18                  | —              | pF            |

**OUTPUT TRANSISTOR**

|                                                                                                                      |                                     |               |    |               |                |                     |
|----------------------------------------------------------------------------------------------------------------------|-------------------------------------|---------------|----|---------------|----------------|---------------------|
| Collector-Emitter Dark Current<br>( $V_{CE} = 10\text{ V}$ , $T_A = 25^\circ\text{C}$ )<br>$T_A = 100^\circ\text{C}$ | CNY17-1,2<br>CNY17-3<br>All devices | $I_{CEO}$     | —  | 5<br>5<br>1.6 | 50<br>100<br>— | nA<br>$\mu\text{A}$ |
| Collector-Base Dark Current ( $V_{CB} = 10\text{ V}$ )                                                               |                                     | $I_{CBO}$     | —  | 0.5           | —              | nA                  |
| Collector-Emitter Breakdown Voltage ( $I_C = 1\text{ mA}$ )                                                          |                                     | $V_{(BR)CEO}$ | 70 | 120           | —              | Volts               |
| Collector-Base Breakdown Voltage ( $I_C = 100\text{ }\mu\text{A}$ )                                                  |                                     | $V_{(BR)CBO}$ | 70 | 120           | —              | Volts               |
| Emitter-Base Breakdown Voltage ( $I_E = 100\text{ }\mu\text{A}$ )                                                    |                                     | $V_{(BR)EBO}$ | 7  | 7.8           | —              | Volts               |
| DC Current Gain ( $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ )                                                      |                                     | $h_{FE}$      | —  | 400           | —              | —                   |
| Collector-Emitter Capacitance ( $f = 1\text{ MHz}$ , $V_{CE} = 0$ )                                                  |                                     | $C_{CE}$      | —  | 8             | —              | pF                  |
| Collector-Base Capacitance ( $f = 1\text{ MHz}$ , $V_{CB} = 0$ )                                                     |                                     | $C_{CB}$      | —  | 21            | —              | pF                  |
| Emitter-Base Capacitance ( $f = 1\text{ MHz}$ , $V_{EB} = 0$ )                                                       |                                     | $C_{EB}$      | —  | 8             | —              | pF                  |

**COUPLED**

|                                                                                                                                                                                                                    |                               |               |                |               |                 |               |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|---------------|----------------|---------------|-----------------|---------------|
| Output Collector Current<br>( $I_F = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$ )                                                                                                                                       | CNY17-1<br>CNY17-2<br>CNY17-3 | $I_C$         | 4<br>6.3<br>10 | 6<br>10<br>15 | 8<br>12.5<br>20 | mA            |
| Collector-Emitter Saturation Voltage ( $I_C = 2.5\text{ mA}$ , $I_F = 10\text{ mA}$ )                                                                                                                              |                               | $V_{CE(sat)}$ | —              | 0.18          | 0.4             | Volts         |
| Delay Time ( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 75\text{ }\Omega$ , Figure 11)                                                                                                                  |                               | $t_d$         | —              | 1.6           | 5.6             | $\mu\text{s}$ |
| Rise Time ( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 75\text{ }\Omega$ , Figure 11)                                                                                                                   |                               | $t_r$         | —              | 1.6           | 4               | $\mu\text{s}$ |
| Storage Time ( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 75\text{ }\Omega$ , Figure 11)                                                                                                                |                               | $t_s$         | —              | 0.7           | 4.1             | $\mu\text{s}$ |
| Fall Time ( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 75\text{ }\Omega$ , Figure 11)                                                                                                                   |                               | $t_f$         | —              | 2.3           | 3.5             | $\mu\text{s}$ |
| Delay Time<br>( $I_F = 20\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-1<br>( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-2,3   |                               | $t_d$         | —<br>—         | 1.2<br>1.8    | 5.5<br>8        | $\mu\text{s}$ |
| Rise Time<br>( $I_F = 20\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-1<br>( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-2,3    |                               | $t_r$         | —<br>—         | 3.3<br>5      | 4<br>6          | $\mu\text{s}$ |
| Storage Time<br>( $I_F = 20\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-1<br>( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-2,3 |                               | $t_s$         | —<br>—         | 4.4<br>2      | 34<br>39        | $\mu\text{s}$ |
| Fall Time<br>( $I_F = 20\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-1<br>( $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$ , Figure 11) CNY17-2,3    |                               | $t_f$         | —<br>—         | 9.7<br>9.4    | 20<br>24        | $\mu\text{s}$ |
| Isolation Voltage ( $f = 60\text{ Hz}$ , $t = 1\text{ sec}$ )                                                                                                                                                      |                               | $V_{ISO}$     | 7500           | —             | —               | Vac(pk)       |
| Isolation Resistance ( $V = 500\text{ V}$ )                                                                                                                                                                        |                               | $R_{ISO}$     | $10^{11}$      | —             | —               | $\Omega$      |
| Isolation Capacitance ( $V = 0$ , $f = 1\text{ MHz}$ )                                                                                                                                                             |                               | $C_{ISO}$     | —              | 0.2           | 0.5             | pF            |

TYPICAL CHARACTERISTICS

T-41-83

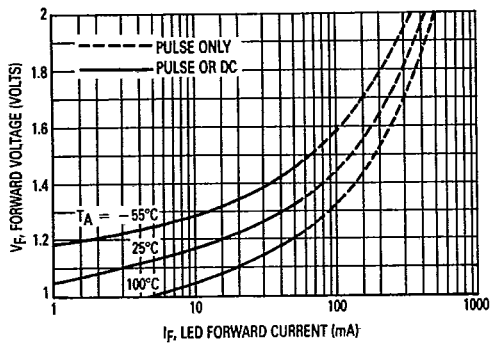


Figure 1. LED Forward Voltage versus Forward Current

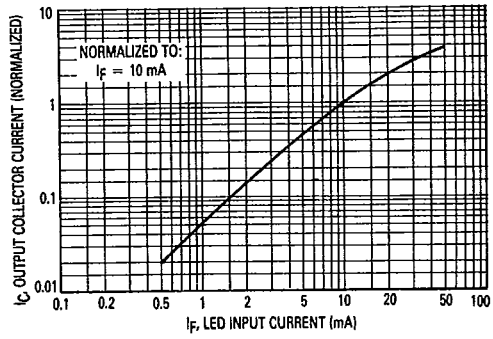


Figure 2. Output Current versus Input Current

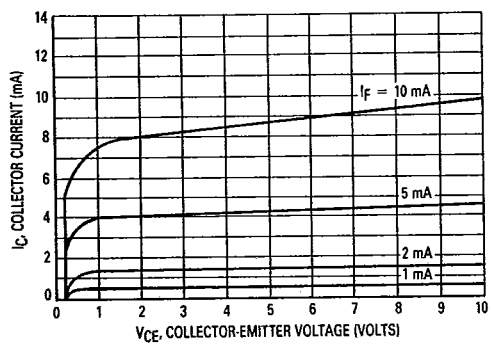


Figure 3. Collector Current versus Collector-Emitter Voltage

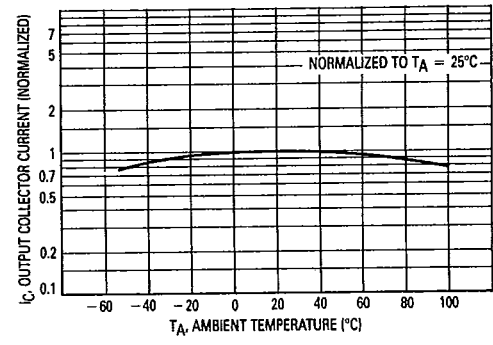


Figure 4. Output Current versus Ambient Temperature

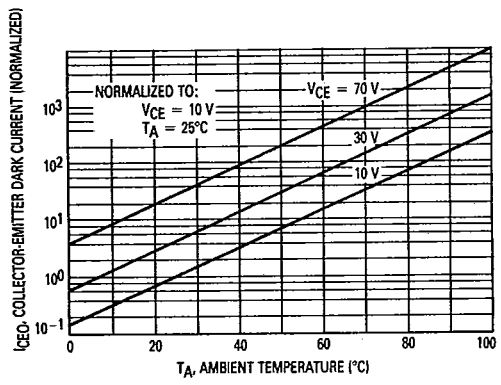


Figure 5. Dark Current versus Ambient Temperature

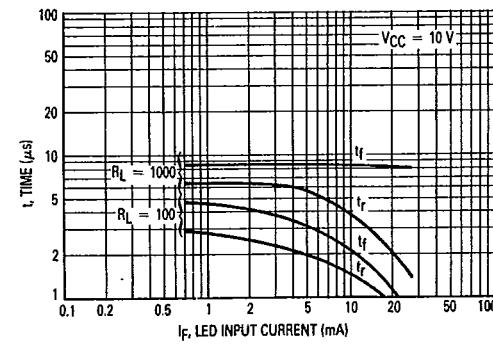


Figure 6. Rise and Fall Times

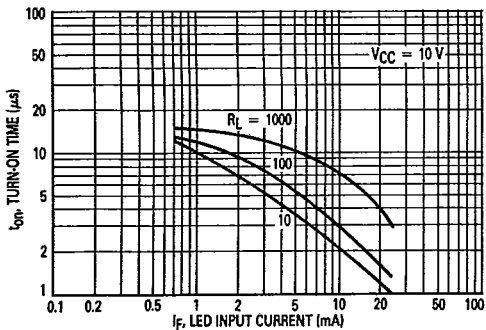


Figure 7. Turn-On Switching Times

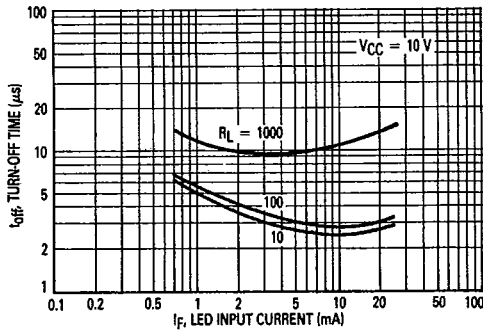


Figure 8. Turn-Off Switching Times

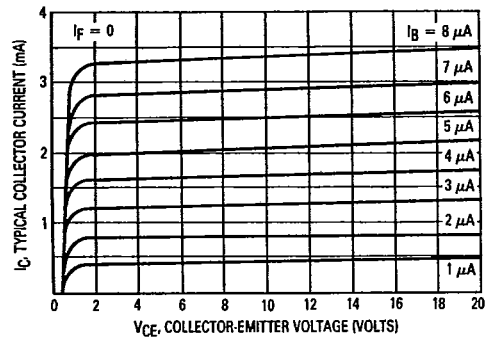


Figure 9. DC Current Gain (Detector Only)

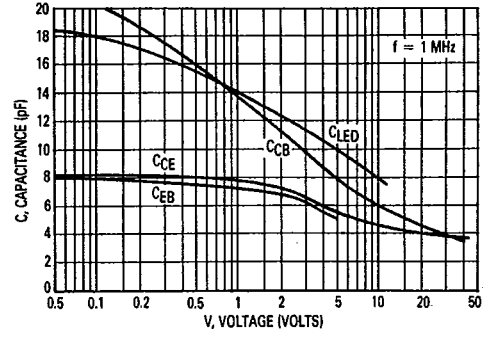


Figure 10. Capacitances versus Voltage

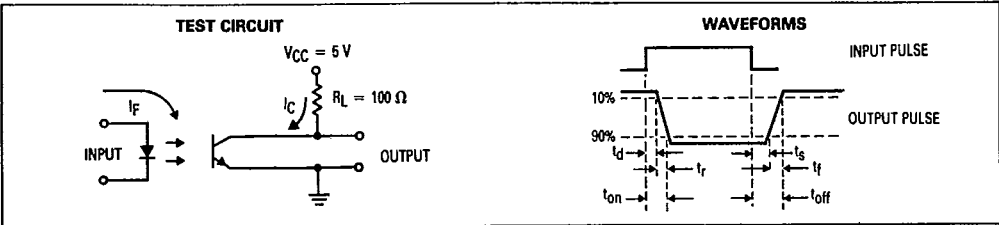
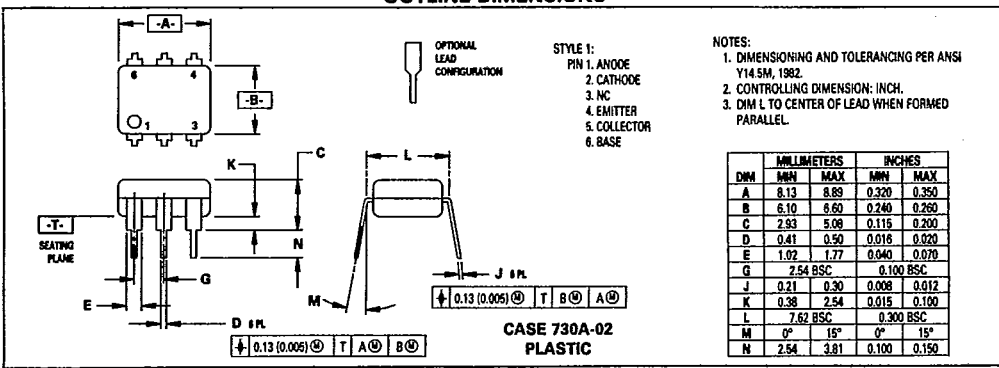


Figure 11. Switching Times



6

T-90-20

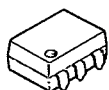
## Optoisolator Lead Form Options

All Motorola 6-pin dual-in-line optoisolators are available in either a surface-mountable gull-wing lead form or a wide-spaced 0.400" lead form, which is used to satisfy 8 mm pc board spacing requirements.

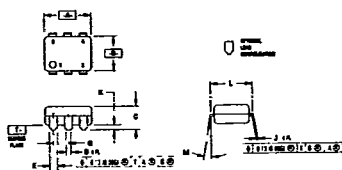
- Attach "R" to any Motorola 6-pin dual-in-line part number for surface-mountable butt-lead option.
- Attach "S" to any Motorola 6-pin dual-in-line part number for surface-mountable gull-wing lead form.
- Attach "T" to any Motorola 6-pin dual-in-line part number for wide-spaced 0.400" lead form.

**Suffix R**  
**Suffix S**  
**Suffix T**

**OPTOISOLATOR  
LEAD FORM  
OPTIONS**

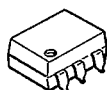
**R**

**Surface-mountable  
butt-lead option**

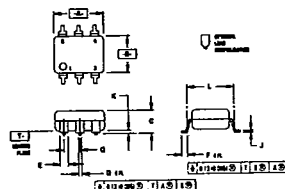
**NOTES:**

1. DIMENSIONS "A" AND "B" ARE DATUMS.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
4. CONTROLLING DIMENSION: INCH.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 8.13        | 8.83 | 0.320     | 0.350 |
| B   | 6.10        | 6.60 | 0.240     | 0.260 |
| C   | 2.93        | 5.08 | 0.115     | 0.200 |
| D   | 0.41        | 0.50 | 0.016     | 0.020 |
| E   | 1.02        | 1.77 | 0.040     | 0.070 |
| G   | 2.54 BSC    |      | 0.100 BSC |       |
| J   | 0.20        | 0.30 | 0.008     | 0.012 |
| K   | 0.51        | 0.63 | 0.020     | 0.025 |
| L   | 7.62 BSC    |      | 0.300 BSC |       |
| M   | 0"          | 15"  | 0"        | 15"   |

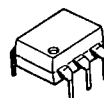
**730B-02****S**

**Surface-mountable  
gull-wing option**

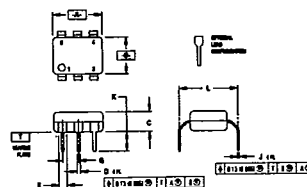
**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 8.13        | 8.83 | 0.320     | 0.350 |
| B   | 6.10        | 6.60 | 0.240     | 0.260 |
| C   | 2.93        | 5.08 | 0.115     | 0.200 |
| D   | 0.41        | 0.50 | 0.016     | 0.020 |
| E   | 1.02        | 1.77 | 0.040     | 0.070 |
| F   | 0.16        | 0.98 | 0.006     | 0.039 |
| G   | 2.54 BSC    |      | 0.100 BSC |       |
| J   | 0.20        | 0.30 | 0.008     | 0.012 |
| K   | 0.51        | 0.63 | 0.020     | 0.025 |
| L   | 8.13 BSC    |      | 0.320 BSC |       |

**730C-02****T**

**Wide-spaced (0.400")  
lead form option**

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIM L TO CENTER OF LEAD WHEN FORMED PARALLEL.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 8.13        | 8.83 | 0.320     | 0.350 |
| B   | 6.10        | 6.60 | 0.240     | 0.260 |
| C   | 2.93        | 5.08 | 0.115     | 0.200 |
| D   | 0.41        | 0.50 | 0.016     | 0.020 |
| E   | 1.02        | 1.77 | 0.040     | 0.070 |
| G   | 2.54 BSC    |      | 0.100 BSC |       |
| J   | 0.20        | 0.30 | 0.008     | 0.012 |
| K   | 3.30        | —    | 0.133     | —     |
| L   | 10.16 BSC   |      | 0.400 BSC |       |

**730D-02**